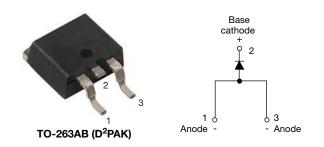
Vishay Semiconductors

# Surface Mount Fast Soft Recovery Rectifier Diode, 10 A



www.vishay.com

ISHA

| PRODUCT SUMMARY                  |                               |  |  |
|----------------------------------|-------------------------------|--|--|
| Package                          | TO-263AB (D <sup>2</sup> PAK) |  |  |
| I <sub>F(AV)</sub>               | 10 A                          |  |  |
| V <sub>R</sub>                   | 1000 V, 1200 V                |  |  |
| V <sub>F</sub> at I <sub>F</sub> | 1.33 V                        |  |  |
| I <sub>FSM</sub>                 | 155 A                         |  |  |
| t <sub>rr</sub>                  | 80 ns                         |  |  |
| T <sub>J</sub> max.              | 150 °C                        |  |  |
| Diode variation                  | Single die                    |  |  |
| Snap factor                      | 0.6                           |  |  |

#### **FEATURES**

- Glass passivated pellet chip junction
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Designed and qualified according to JEDEC<sup>®</sup>-JESD 47



• Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

#### APPLICATIONS

- Output rectification and freewheeling in inverters, choppers and converters
- Input rectifications where severe restrictions on conducted EMI should be met

#### DESCRIPTION

The VS-10ETF..SPbF fast soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

| MAJOR RATINGS AND CHARACTERISTICS |                              |             |       |  |  |
|-----------------------------------|------------------------------|-------------|-------|--|--|
| SYMBOL                            | CHARACTERISTICS              | VALUES      | UNITS |  |  |
| I <sub>F(AV)</sub>                | Sinusoidal waveform          | 10          | A     |  |  |
| V <sub>RRM</sub>                  |                              | 1000/1200   | V     |  |  |
| I <sub>FSM</sub>                  |                              | 155         | A     |  |  |
| V <sub>F</sub>                    | 10 A, T <sub>J</sub> = 25 °C | 1.33        | V     |  |  |
| t <sub>rr</sub>                   | 1 A, 100 A/µs                | 80          | ns    |  |  |
| TJ                                | Range                        | -40 to +150 | °C    |  |  |

| VOLTAGE RATINGS |   |  |                                     |  |  |
|-----------------|---|--|-------------------------------------|--|--|
| PART NUMBER     | V <sub>RRM</sub> , MAXIMUM PEAK<br>REVERSE VOLTAGE<br>V | V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE<br>PEAK REVERSE VOLTAGE<br>V | I <sub>RRM</sub><br>AT 150 °C<br>mA |  |  |
| VS-10ETF10SPbF  | 1000  | 1100   | 4                                   |  |  |
| VS-10ETF12SPbF  | 1200  | 1300   | 4                                   |  |  |

| ABSOLUTE MAXIMUM RATINGS                     |                    |  |        |                  |
|--|--------------------|--|--------|------------------|
| PARAMETER                                    | SYMBOL             | TEST CONDITIONS                                  | VALUES | UNITS            |
| Maximum average forward current              | I <sub>F(AV)</sub> | $T_C$ = 125 °C, 180° conduction half sine wave   | 10     |                  |
| Maximum peak one cycle non-repetitive        | <b>I</b>           | 10 ms sine pulse, rated V <sub>RRM</sub> applied | 130    | А                |
| surge current                                | I <sub>FSM</sub>   | 10 ms sine pulse, no voltage reapplied           | 155    |                  |
| Maximum I <sup>2</sup> t for fusing          | l <sup>2</sup> t   | 10 ms sine pulse, rated V <sub>RRM</sub> applied | 85     | A <sup>2</sup> s |
|  |                    | 10 ms sine pulse, no voltage reapplied           | 120    | A-5              |
| Maximum I <sup>2</sup> $\sqrt{t}$ for fusing | l²√t               | t = 0.1 ms to 10 ms, no voltage reapplied        | 1200   | A²√s             |

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### **VS-10ETF..SPbF Series**



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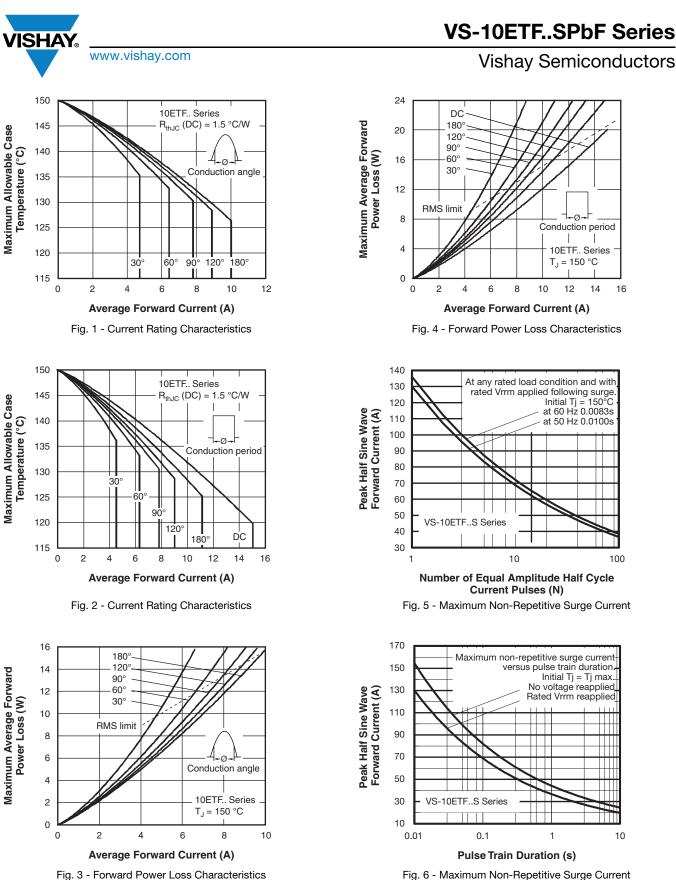
| ELECTRICAL SPECIFICATIONS       |                    |                              |                       |        |       |
|---------------------------------|--------------------|------------------------------|-----------------------|--------|-------|
| PARAMETER                       | SYMBOL             | TEST CONDITIONS              |                       | VALUES | UNITS |
| Maximum forward voltage drop    | V <sub>FM</sub>    | 10 A, T <sub>J</sub> = 25 °C |                       | 1.33   | V     |
| Forward slope resistance        | r <sub>t</sub>     | T <sub>J</sub> = 150 °C      |                       | 22.9   | mΩ    |
| Threshold voltage               | V <sub>F(TO)</sub> |                              |                       | 0.96   | V     |
|                                 |                    | T <sub>J</sub> = 25 °C       | V - Reted V           | 0.1    | mA    |
| Maximum reverse leakage current | IRM                | T <sub>J</sub> = 150 °C      | $V_R = Rated V_{RRM}$ | 4      | ША    |

| RECOVERY CHARACTERISTICS |                 |                                      |        |       |                        |
|--------------------------|-----------------|--------------------------------------|--------|-------|------------------------|
| PARAMETER                | SYMBOL          | TEST CONDITIONS                      | VALUES | UNITS | · •                    |
| Reverse recovery time    | t <sub>rr</sub> | I <sub>F</sub> at 10 A <sub>pk</sub> | 310    | ns    | I <sub>FM</sub>        |
| Reverse recovery current | Irr             | 25 A/µs                              | 4.7    | А     |                        |
| Reverse recovery charge  | Q <sub>rr</sub> | 25 °C                                | 1.05   | μC    |                        |
| Typical snap factor      | S               |                                      | 0.6    |       | I I <sub>RM(REC)</sub> |

| THERMAL - MECHANICAL SPECIFICATIONS                         |                                   |   |             |       |
|---|-----------------------------------|---|-------------|-------|
| PARAMETER   | SYMBOL                            | TEST CONDITIONS                         | VALUES      | UNITS |
| Maximum junction and storage temperature range              | T <sub>J</sub> , T <sub>Stg</sub> |   | -40 to +150 | °C    |
| Maximum thermal resistance, junction to case                | R <sub>thJC</sub>                 | DC operation                            | 1.5         | °C/W  |
| Maximum thermal resistance, junction to ambient (PCB mount) | R <sub>thJA</sub> <sup>(1)</sup>  |   | 62          | 0/10  |
| Soldering temperature                                       | T <sub>S</sub>                    |   | 260         | °C    |
| Approvimete weight  |                                   |   | 2           | g     |
| Approximate weight  |                                   |   | 0.07        | oz.   |
| Marking daviaa  |                                   |   |             | =10S  |
| Marking device  |                                   | Case style D <sup>2</sup> PAK (SMD-220) | 10ETF       | =12S  |

Note

<sup>(1)</sup> When mounted on 1" square (650 mm<sup>2</sup>) PCB of FR-4 or G-10 material 4 oz. (140 μm) copper 40 °C/W. For recommended footprint and soldering techniques refer to application note #AN-994.



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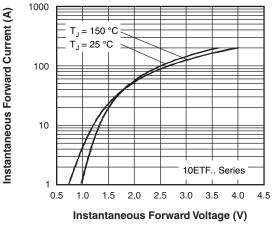


Fig. 7 - Forward Voltage Drop Characteristics

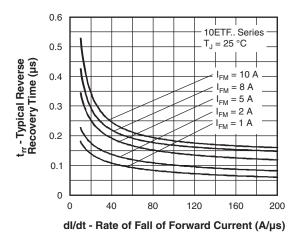


Fig. 8 - Recovery Time Characteristics, T<sub>J</sub> = 25 °C

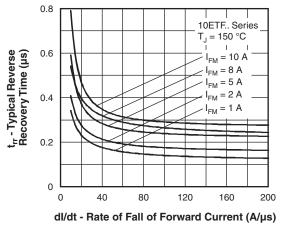


Fig. 9 - Recovery Time Characteristics,  $T_J$  = 150 °C

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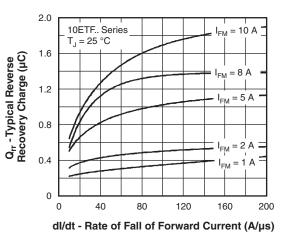


Fig. 10 - Recovery Charge Characteristics,  $T_J = 25$  °C

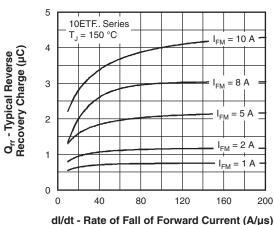




Fig. 11 - Recovery Charge Characteristics,  $T_{\rm J}$  = 150  $^\circ\text{C}$ 

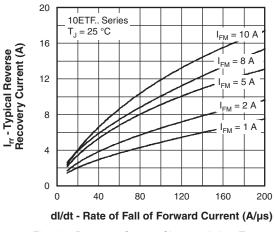


Fig. 12 - Recovery Current Characteristics,  $T_J$  = 25  $^\circ\text{C}$ 

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## **VS-10ETF..SPbF Series**

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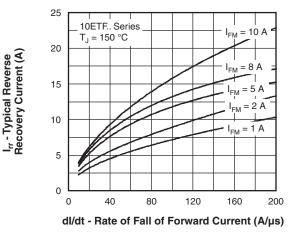
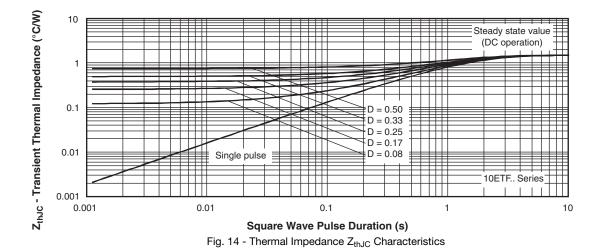
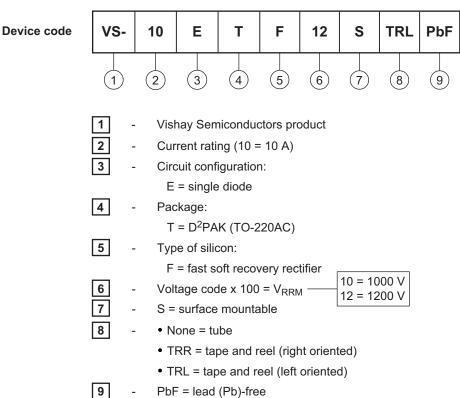


Fig. 13 - Recovery Current Characteristics, T<sub>J</sub> = 150 °C



VS-10ETF12STRLPbF

# **ORDERING INFORMATION TABLE**



| ORDERING INFORMATION (Example) |                  |                        |                          |  |  |  |
|--------------------------------|------------------|------------------------|--------------------------|--|--|--|
| PREFERRED P/N                  | QUANTITY PER T/R | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION    |  |  |  |
| VS-10ETF10SPbF                 | 50               | 1000                   | Antistatic plastic tubes |  |  |  |
| VS-10ETF10STRRPbF              | 800              | 800                    | 13" diameter reel        |  |  |  |
| VS-10ETF10STRLPbF              | 800              | 800                    | 13" diameter reel        |  |  |  |
| VS-10ETF12SPbF                 | 50               | 1000                   | Antistatic plastic tubes |  |  |  |
| VS-10ETF12STRRPbF              | 800              | 800                    | 13" diameter reel        |  |  |  |

800

| LINKS TO RELATED DOCUMENTS                 |                          |  |  |
|--|--------------------------|--|--|
| Dimensions <u>www.vishay.com/doc?95046</u> |                          |  |  |
| Part marking information                   | www.vishay.com/doc?95054 |  |  |
| Packaging information                      | www.vishay.com/doc?95032 |  |  |

800



## VS-10ETF..SPbF Series

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13" diameter reel



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